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Ligand-induced reduction concerted with coating by atomic layer deposition on the example of TiO_2 -coated magnetite nanoparticles†

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Atomic layer deposition is a chemical deposition technology that provides ultimate control over the conformality of films and their thickness, even down to Ångström-scale precision. Based on the marked superficial character and gas phase process of the technique, metal sources and their ligands shall ideally be highly volatile. However, in numerous cases those ligands corrode the substrate or compete for adsorption sites, well-known as side reactions of these processes. Therefore, the ability to control such side reactions might be of great interest, since it could achieve synchronous coating and alteration of a substrate in one process, saving time and energy otherwise needed for a post-treatment of the sample. Consequently, advances in this way must require understanding and control of the chemical processes that occur during the coating. In this work, we show how choosing an appropriate ligand of the metal source can unveil a novel approach to concertedly coat and reduce $\gamma\text{-Fe}_2\text{O}_3$ nanoparticles to form a final product composed of $\text{Fe}_3\text{O}_4/\text{TiO}_2$ core/shell nanoparticles. To this aim, we envisage that appropriate design of precursors and selection of substrates will pave the way for numerous new compositions, while the ALD process itself allows for easy upscaling to large amounts of coated and reduced particles for industrial use.

Introduction

Atomic layer deposition (ALD)^{1–3} is a coating technology that in recent years became indispensable in microelectronics^{4,5} and it enjoys a rapidly growing interest for emerging applications in energy storage,^{6–9} medicine,^{10–12} etc. The reason is that ALD provides ultimate control over the conformality of films and their thickness, even down to Ångström-scale precision.¹³ ALD relies on the temporal separation of two or more chemical precursors and their individual surface reactions on the substrate surface upon exposure. The reactions are self-saturating in each reaction stage, ensuring that one complete ALD cycle can only result in a maximum of one monolayer coating. Repeating an ALD cycle adds another layer and allows

the coating thickness to be precisely controlled with the choice of the number of processing cycles.¹⁴ In contrast to CVD, which requires higher temperatures and simultaneous delivery of two or more precursors, ALD can be performed at comparatively lower temperatures and the deposition will be truly non-directional.¹⁵

An important aspect of ALD is that it is a chemical deposition technology and as such requires understanding and control of the chemical processes that occur during the coating. Most considerations for the development of a process are directed towards the precursor chemistry, which is usually thoughtfully designed to enable a rapid process with ideally no impurities in the growing film and no corrosion or any other kind of harm to the coated substrate. Typically, metalorganic, organometallic or halide compounds are utilized as metal sources for coatings and the ligands of those compounds shall ideally be highly volatile.^{16–19} However, in numerous cases those ligands corrode the substrate or compete for adsorption sites,^{20,21} which are side reactions of such processes. Typically, such side reactions are unwanted, and precursors are chosen which will not release reactive ligands or intermediates. The ability to control such side reactions might, however, be of great interest, since one could achieve synchronous coating and alteration of a substrate in one process, thus saving time and energy otherwise needed for post-treatment of the sample. One such scenario refers to the oxidation state of a substrate material. Since most ALD

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† Electronic supplementary information (ESI) available: Magnetization vs. temperature graphics of comparison samples. List of possible reaction schemes and DFT calculated reaction energies for reducing Fe_2O_3 to Fe_3O_4 by using different ALD precursors. XRD patterns of TiO_2 -coated (TDMATi- FeO_x) and uncoated FeO_x nanoparticles before and after the annealing process. See DOI: [10.1039/c8sc04474k](https://doi.org/10.1039/c8sc04474k)



processes operate with a counter precursor that contains oxygen, for example, water vapor, oxygen plasma or ozone, it becomes difficult to preserve or achieve a reduced state of a metal during the process, particularly in those cases where the metal is prone to easy oxidation. The choice of a precursor which contains ligands that upon release can reduce the substrate can be beneficial as it would avoid the need for post-processing, for example in the form of reductive annealing. In the case of powders, the applied ALD process itself allows for easy upscaling to large amounts of coated and reduced particles for industrial use. Nowadays, the most well-known reactors for this purpose are the so-called fluidized bed reactors and rotatory reactors. Such reactors provide conformal film deposition on large amounts of particles by ALD for emerging applications.^{22–27}

The combination of $\text{TiO}_2/\text{FeO}_x$ in the synthesis of core/shell nanoparticles and its induced chemical reduction reach a wide range of functionalities for various applied materials. Nano-scale titanium dioxide (TiO_2) found applications as a UV light attenuator. The incorporation of this material in sunscreens, cosmetics, clothes and plastic containers has successfully been demonstrated.²⁸ Besides, its photocatalytic activity is beneficial for the removal of persistent organic pollutants and thus for recycling waste water.²⁹ The recollection of such nanoparticles from water, however, poses a problem. A way to address this is to combine TiO_2 with magnetic materials, such as iron oxide, which allows a convenient recovery of the catalyst under an external magnetic field.³⁰

The potential uses of such combined materials are not limited to this application. If one looks at the same materials from the perspective of magnetic properties, the great biocompatibility of titanium dioxide in combination with superparamagnetic particles opens the door to a wide range of applications such as, targeted drug delivery,³¹ magnetic resonance imaging,³² hyperthermia,³³ magnetic separation of biomolecules,³⁴ and sensing applications.³⁵

Herein, we report the synthesis of $\text{Fe}_3\text{O}_4/\text{TiO}_2$ core/shell nanoparticles by ALD at moderate temperatures. We apply an ALD process, which involves two independent and concerted chemical reactions. As a substrate we use commercial iron oxide nanoparticles and as precursors, Ti-based precursors and deionized water. We demonstrate how it is possible to coat and reduce, at the same time, iron oxide particles depending on the existing ligand in the selected metal-based precursor. In other words, while the ALD process to coat the particles with TiO_2 takes place, the Fe^{3+} ions in the seed nanoparticles can be partially reduced to Fe^{2+} , enforcing the transformation of $\gamma\text{-Fe}_2\text{O}_3$ to the well-known magnetite, Fe_3O_4 , structure. The resulting core/shell particles have been systematically studied by X-ray diffraction, magnetometry, energy dispersive X-ray analysis and electron microscopy. The underlying mechanism of the reduction reaction was further modelled by density functional theory. Upon comparisons with various optional Ti-precursors, the study showed that the ligands of the titanium precursor tetrakis(dimethylamino)titanium(iv) (TDMATi) are responsible for the partial reduction of Fe^{3+} by forming tetramethyl hydrazine as a byproduct during the corresponding

oxidation reaction. Both, simulation and experiment show that only this type of precursor enables the synchronous coating-reduction reaction, while the energy barriers for a reduction are too high in the case of alternative choices of precursors. They will only yield a coating of the particles. This finding opens the possibility to design novel ALD precursors for a combined one-step capping and reduction process for the synthesis of further material combinations.

Results and discussion

Commercial $\gamma\text{-Fe}_2\text{O}_3$ nanoparticles (sample FeO_x) have been coated with TiO_2 by ALD using, at a first stage, TDMATi and water as precursors (sample TDMATi- FeO_x). Fig. 1(a) shows X-ray diffraction (XRD) patterns obtained from the samples before and after ALD coating. Both diffraction patterns are very similar showing characteristic peaks of the cubic spinel structure stemming from the iron oxide. It should be noted that no characteristic peaks from titanium oxide are seen, which is due to the amorphous character of the TiO_2 deposited under the applied processing conditions.

However, the transmission electron micrographs show the formation of a core/shell structure. In Fig. 2 the core/shell construction of the nanoparticles is very obvious both from the contrast in scanning transmission electron microscopy (STEM) as well as the energy-dispersive X-ray spectroscopy (EDX) images, which show the involved elements in different colors. A more detailed analysis of the XRD patterns of samples FeO_x and TDMATi- FeO_x shows a clear alteration of the pristine iron oxide structure after the ALD process. While both patterns reveal the presence of a cubic spinel structure, the shift in their diffraction peaks and the concomitant variation of their cell parameter point towards the presence of two different iron oxide phases in the two samples.

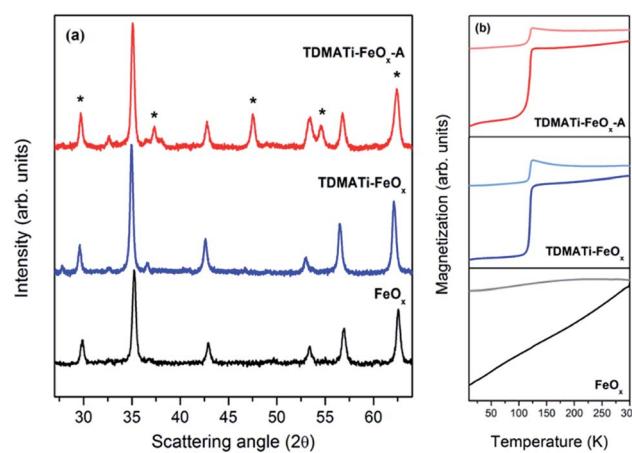


Fig. 1 (a) XRD patterns of uncoated $\gamma\text{-Fe}_2\text{O}_3$ particles (FeO_x) and TiO_2 -coated $\gamma\text{-Fe}_2\text{O}_3$ nanoparticles with TDMATi and H_2O as precursors, before annealing (TDMATi- FeO_x) and after annealing at 470 °C (TDMATi- FeO_x -A). (b) Magnetization curves vs. temperature for the samples in (a). * denotes diffraction peaks originating from TiO_2 .



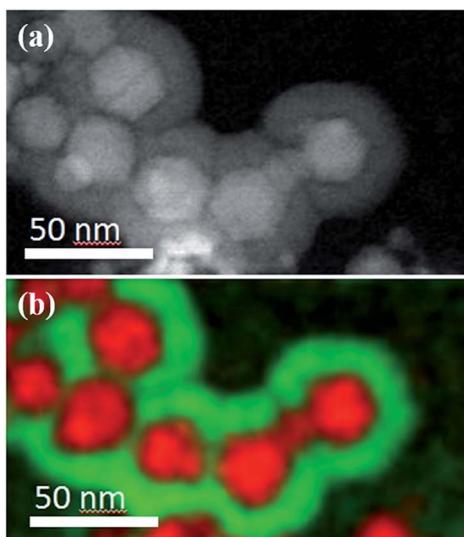


Fig. 2 (a) STEM micrograph and (b) STEM-EDX map of Fe_3O_4 (red)/ TiO_2 (green) core/shell nanoparticles.

The commercial particles have a cell parameter of $8.347(5)$ Å (see Table 1) which is characteristic of completely oxidized maghemite, $\gamma\text{-Fe}_2\text{O}_3$ (JCPDS card no. 39-1346), where Fe^{3+} cations occupy the octahedral and tetrahedral sites of the structure. In contrast, the sample TDMATi– FeO_x shows an increase of the cell parameter to a value of $8.390(5)$ Å (see Table 1), which is characteristic of a partial $\text{Fe}^{3+} \rightarrow \text{Fe}^{2+}$ reduction of the octahedral cations to form the well-known magnetite, Fe_3O_4 , structure (JCPDS card no. 19-629). Note that the crystal size of both samples is very similar with values of roughly 30 nm. The expected change of the volume of about 6% after the ALD process is not notable from Rietveld-based XRD measurements, since the resolution is not high enough for clearly confirming such small changes.

In order to gain more insight into the phase transformation observed after the ALD process we compared the magnetic properties of both samples by measuring their magnetization temperature curves under both field cooling (FC) and zero field cooling (ZFC) conditions (see Fig. 1(b)). Both samples depict the expected behavior of nanostructured magnetic nanoparticles where the FC and ZFC curves are distinct at low temperatures

and tend to converge at the so-called blocking temperature (T_B).³⁶ Indeed, for such large iron oxide particles (*i.e.*, 30 nm) this transition was observed at temperatures above RT.³⁷ The sample TDMATi– FeO_x shows a similar trend to the untreated sample, but with an extrapolated T_B at higher temperatures. More interesting is, however, another magnetic transition that can be clearly observed at 120 K and can be ascribed to the Verwey temperature (T_V) of Fe_3O_4 . This transition is characteristic of Fe_3O_4 which undergoes a transformation from cubic ($T > T_V$) to monoclinic ($T < T_V$) symmetry.³⁸ Such transformation is related to modifications in the crystal symmetry and the cation ordering and is accompanied by dramatic changes in electrical conductivity and heat capacity. Given the results of the magnetic characterization, it can be stated that the iron in the commercial particles (FeO_x) suffered a transformation from a completely oxidized state, typical of maghemite ($\gamma\text{-Fe}_2\text{O}_3$), to a partially reduced state as it is typical of magnetite during the ALD process.

For crystallographic confirmation of the deposition of titanium oxide over the iron oxide, the particles have been annealed at 470 °C (sample TDMATi– FeO_x -A). Fig. 1(a) shows the evolution of anatase-type TiO_2 (JCPDS card no. 21-1272) after annealing, which resulted from the crystallization of the deposited film. The peaks of the cubic spinel structure of Fe_3O_4 are not affected by the heat treatment, preserving the structure obtained after the ALD process. The magnetization measurement of the particles after annealing further confirms the presence of magnetite showing its characteristic Verwey transition (see Fig. 1(b)). It is interesting to note that no traces of any further iron oxide crystal structure can be found, and the crystal size of the phase is very similar to that of the untreated sample (*i.e.*, 30 nm). Both effects demonstrate that the TiO_2 coating avoids intimate contact between the particles and thus their agglomeration and phase transformation to more stable iron oxide phases (*i.e.*, $\alpha\text{-Fe}_2\text{O}_3$), even if the temperature is increased to 470 °C.³⁹

A further experiment was performed to compare the thermal stability of the material. Uncoated commercial $\gamma\text{-Fe}_2\text{O}_3$ nanoparticles were annealed using the same conditions as those of the sample TDMATi– FeO_x -A (470 °C – 3 h). The results showed that the particles without TiO_2 coating became $\alpha\text{-Fe}_2\text{O}_3$ and their particle size increased from 30 nm to 70 nm due to the partial sintering of the nanoparticles after the thermal

Table 1 Structural properties and Verwey transition of nanoparticles

Sample	Composition	ALD process	Phase	Lattice parameter (Å)	Crystal size (nm)	Verwey transition
FeO_x	Commercial FeO_x	—	$\gamma\text{-Fe}_2\text{O}_3$	$8.347(5)$	$32.5(5)$	No
TDMATi– FeO_x	$\text{TiO}_2/\text{FeO}_x$	TDMATi + H_2O (150 °C)	Fe_3O_4	$8.390(5)$	$31(5)$	Yes
TDMATi– FeO_x -A	$\text{TiO}_2/\text{FeO}_x$, annealed (470 °C)	TDMATi + H_2O (150 °C)	Fe_3O_4	$8.388(5)$	$32(5)$	Yes
			TiO_2	$3.782(5)/9.483(5)$	$23(5)$	
Fe O_x -A	Commercial FeO_x , annealed (470 °C)	—	$\alpha\text{-Fe}_2\text{O}_3$	$5.031(5)/13.738(5)$	$70(5)$	No
TiCl $_4$ – FeO_x	$\text{TiO}_2/\text{FeO}_x$	TiCl $_4$ + H_2O (150 °C)	$\gamma\text{-Fe}_2\text{O}_3$	$8.339(5)$	$28(5)$	No
TDMASn– FeO_x	$\text{SnO}_2/\text{FeO}_x$	TDMASn + H_2O (150 °C)	$\gamma\text{-Fe}_2\text{O}_3$	$8.351(5)$	$23(5)$	No
TDMASn– FeO_x -250	$\text{SnO}_2/\text{FeO}_x$	TDMASn + H_2O (250 °C)	Fe_3O_4	$8.380(5)$	$30(5)$	Yes
TDMAHf– FeO_x	$\text{HfO}_2/\text{FeO}_x$	TDMAHf + H_2O (150 °C)	Fe_3O_4	$8.382(5)$	$44(5)$	Yes



treatment as shown in Table 1. Besides, no reduction of particles was observed in the latter case. Similar structural transformation is expected for the Fe_3O_4 structure as it has already been demonstrated for thin films and nanoparticles.^{40,41}

The TiO_2 coating of iron oxide particles by ALD using TDMATi as the precursor not only protects the nanostructures from oxidation and agglomeration, but also induces a partial reduction of pristine $\gamma\text{-Fe}_2\text{O}_3$ and a concomitant phase transformation. Such a transformation may be triggered by either the metal or the ligand present in the ALD precursor.

Therefore, a series of experiments have been performed in order to identify the source. Firstly, the growth of TiO_2 has been carried out using an alternative titanium precursor (titanium chloride, TiCl_4) in order to identify a potential effect of the titanium ion. In the second stage, the effect of the $(\text{CH}_3)_2\text{N}^-$ ligand has been evaluated by performing ALD coating with another TDMA-based metal precursor, tetrakis(dimethylamino)tin(iv) (TDMSn).

The sample $\text{TiCl}_4\text{-FeO}_x$ has been obtained after an ALD process of the same commercial iron oxide particles using TiCl_4 and demineralized water as precursors at 150 °C. From the Rietveld analysis of the X-ray diffraction data in Fig. 3, it can be observed that after the TiO_2 deposition the cell parameter of the iron oxide core remains similar to that of the pristine sample ($\gamma\text{-Fe}_2\text{O}_3$) (see Table 1). The magnetometric curves show no signs of Verwey transition. Therefore, the titanium cation

appears not to be responsible for the partial reduction of the $\gamma\text{-Fe}_2\text{O}_3$ particles, which is reasonable from the chemical perspective as it is already present in the oxidation state +4 and further oxidation would not be possible under the given conditions.

For investigating the ligand $((\text{CH}_3)_2\text{N}^-)$ as a potential reducing agent, TDMSn and demineralized water were used as precursors in an ALD process at 150 °C (sample TDMSn- FeO_x). Similar to the TiCl_4 ALD process, the crystal structure of the iron oxide particles after using TDMSn seems not to be affected. The particles largely maintain their cell parameters (Table 1) and no presence of Verwey transition is observed.

However, considering the different Pauling electronegativities of Ti and Sn (*i.e.*, 1.54 and 1.96, respectively), the reactivity of the ligand may be strongly affected by the metal cation present in the precursor. Assuming that the energy required for the ligand dissociation from the coordination sphere of the metal in TDMSn is higher than in the case of TDMATi, the ALD process with the tin precursor has been repeated at higher temperatures, namely, at 250 °C (sample TDMSn- FeO_x -250). As a result, the iron oxide nanostructure is affected in a similar manner to that with TDMATi. The cell parameter is increased (Table 1) and the Verwey transition appears in the magnetization curves confirming the $\text{Fe}^{3+} \rightarrow \text{Fe}^{2+}$ partial reduction and, thus, the Fe_3O_4 formation.

Finally, in order to further confirm that the TDMA ligand is responsible for the reduction, a further ALD process with tetrakis(dimethylamino)hafnium(iv) (TDMAHf), sample TDMAHf- FeO_x , as a precursor has been performed. Demineralized water was used as a counter precursor. Hf has an electronegativity similar to that of Ti (*i.e.*, 1.3), which implies that upon correct assumption of the mechanism, similar results to those with TDMATi can be obtained. A partial reduction of $\gamma\text{-Fe}_2\text{O}_3$ may take place already at lower temperatures. Indeed, the Rietveld analysis of the samples TDMAHf- FeO_x shows that the cell parameter is increased after the TDMAHf process to permit the formation of the Fe_3O_4 structure. In the magnetization curves the Verwey transition is clearly observed. Another possible precursor combination involves tetrakis(dimethylamino)zirconium(iv) (TDMAZr) and demineralized water. Zr has an electronegativity of 1.33, a value between the Ti and Hf electronegativities (1.54 and 1.3, respectively). Dennis M. Hausmann *et al.* successfully performed ALD depositions of ZrO_2 with those precursors at 150 °C, under the same process conditions as those used here for TDMA-based precursors. Supposing that the ligand separation and reduction is a function of the Pauling electronegativity and, in consequence, the process temperature, both ZrO_2 deposition and reduction of iron oxide particles are expected from this precursor combination as well.^{42,43}

The results show that the anion of the precursor, $((\text{CH}_3)_2\text{N}^-)$, is responsible for the partial reduction of iron oxide and the concomitant structural modification of the initial seed nanoparticles. In the first step of the ALD process, the TDMATi precursor loses the amino groups while anchoring to the surface of the nanoparticles. Those ligands can lose one electron each and recombine to form gas phase $(\text{CH}_3)_2\text{NN}(\text{CH}_3)_2$

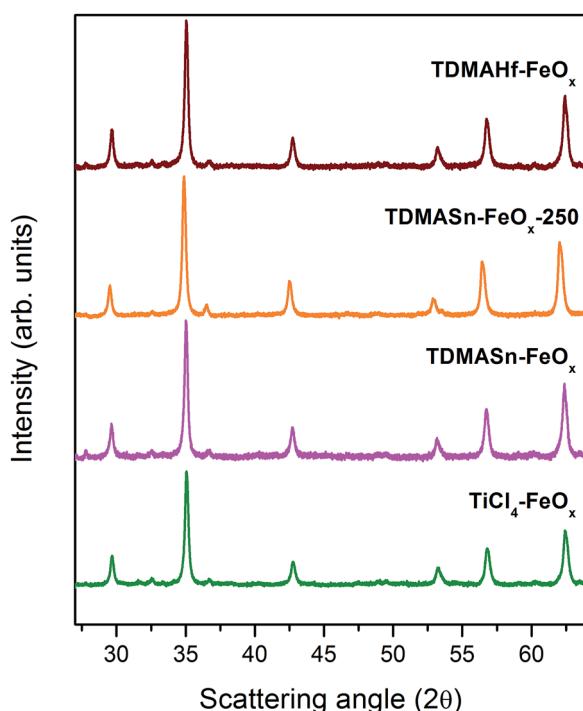


Fig. 3 XRD patterns of TiO_2 -coated $\gamma\text{-Fe}_2\text{O}_3$ nanoparticles with TiCl_4 and H_2O ALD precursors ($\text{TiCl}_4\text{-FeO}_x$), SnO_2 -coated $\gamma\text{-Fe}_2\text{O}_3$ nanoparticles with TDMSn and H_2O ALD precursors, at processing temperatures of 150 °C (TDMSn- FeO_x) and 250 °C (TDMSn- FeO_x -250) and HfO_2 -coated $\gamma\text{-Fe}_2\text{O}_3$ nanoparticles with TDMAHf and H_2O ALD precursors (TDMAHf- FeO_x).



(tetramethylhydrazine), which is the oxidation product as the γ - Fe_2O_3 substrate is being reduced.

We performed a DFT modelling of the reaction energies for such a case and compared it to the model of reactions with different precursors with varying metals and ligands (Fig. 4). Indeed, the calculations show that TDMAHf and TDMAZr have negative reaction energies (-0.37 eV and -0.25 eV, respectively), indicating an excellent capability of reducing γ - Fe_2O_3 to Fe_3O_4 . TDMATi also energetically favours the reduction with an estimated activation barrier of 0.85 eV. However, with increasing the Pauling electronegativity of the central metal atom, as in the case of TDMSn and TDMAIr, the reduction reaction becomes energetically less favourable with larger activation barriers of 1.12 eV and 2.16 eV, respectively, indicating that higher reaction temperatures are needed to induce the reduction. On the other hand, the DFT-calculated reaction models of titanium precursors with different ligands such as titanium isopropoxide $\text{Ti}(\text{O}i\text{Pr})_4$ and TiCl_4 show much higher reaction barriers of 4.08 eV and 4.45 eV, respectively, meaning that no reduction is expected with those precursor families.

These theoretical results well explain the phenomena observed experimentally and support the importance of precursor ligands for such concerted reduction-coating processes. When an ALD process is carried out, the electrons originating from the amino ligands of TDMATi create a chemical potential gradient at the nanoparticle surface triggering the reduction process along the whole iron oxide structure. This hypothesis is supported by the magnetometric curves measured after different ALD cycle numbers and the visual color change of the particles after the ALD process (Fig. 5). The characteristic T_v of the Fe_3O_4 structure appears already after the first ALD cycle and becomes more pronounced as the number of cycles increases, which is very likely related to a mediated diffusion and growth mechanism.⁴⁴ Therefore, even though the experiments were carried out with nanoparticles of approximately 50 nm in size, it can be assumed that the reduction process,

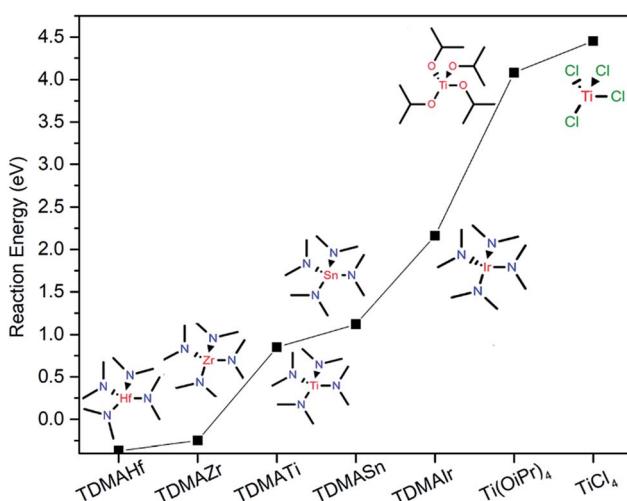


Fig. 4 Comparison of the DFT-calculated reaction energies of reducing Fe_2O_3 to Fe_3O_4 by using different ALD precursors.

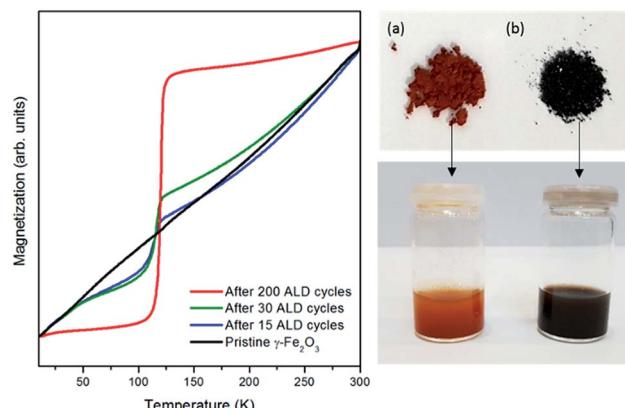


Fig. 5 Left panel: magnetization vs. temperature curves of $\text{Fe}_3\text{O}_4/\text{TiO}_2$ core/shell nanoparticles after various numbers of ALD coating cycles and a concerted reduction of the γ - Fe_2O_3 nanoparticles to Fe_3O_4 . Right panel: visual color change of the particles in powder form (top) and dispersed in water (bottom); (a) untreated commercial γ - Fe_2O_3 nanoparticles, and (b) the same particles after applying various ALD cycles, forming $\text{Fe}_3\text{O}_4/\text{TiO}_2$ core/shell nanoparticles. The color change from orange to black is indicative of a transformation from γ - Fe_2O_3 to magnetite.

which affects only the surface in contact with the precursors, will be to a large extent independent of the particle size. Therefore, the concerted process presented in this work can be envisaged for larger particle sizes and thin films as well. The porosity of the substrate plays a role in the process as it supports the diffusion of the precursors and the reduction of the substrate. Besides, it is possible to appreciate visually the color change from orange, in commercial γ - Fe_2O_3 , to black, after the reduction to Fe_3O_4 (see Fig. 5).

Experimental

Sample preparation

All samples were prepared following the same procedure. Commercial maghemite (γ - Fe_2O_3) nanoparticles with a particle size less than 50 nm, (CAS: 1309-37-1) from Sigma Aldrich, were dispersed in ethanol and sonicated for 15 minutes for better dispersion. Thereafter, the nanoparticles were spread over fused quartz substrates and dried for 24 hours. Prior to loading, the fused quartz substrates were cleaned in an ultrasonicator using acetone and then ethanol and blown dry using nitrogen gas.⁴⁵

ALD process

The coating of the nanoparticles was performed in a commercial ALD reactor (Savannah S100, Cambridge NanoTech Inc). The processes were carried out under a constant nitrogen gas flow rate of 20 standard cubic centimeters per minute (sccm).

Various metal-containing ALD precursors have been used for the coating of the nanoparticles, including tetrakis(dimethylamino)titanium(iv) (TDMATi, $[(\text{CH}_3)_2\text{N}]_4\text{Ti}$), titanium chloride (TiCl_4), tetrakis(dimethylamino)tin(iv) (TDMSn, $[(\text{CH}_3)_2\text{N}]_4\text{Sn}$) and tetrakis(dimethylamino)hafnium(iv) (TDMAHf, $[(\text{CH}_3)_2\text{N}]_4\text{Hf}$), all of which were obtained from Sigma Aldrich. Demineralized



water was used as the oxygen source. The coated nanoparticles were prepared following a typical ALD timing sequence expressed as $t_1-t_2-t_3-t_4$, where t_1 is the exposure time to the first precursor, t_2 is the purge time following the first exposure, t_3 is the exposure time to the second precursor, and t_4 is the purge time following the exposure to the second precursor. The times corresponding to $t_1-t_2-t_3-t_4$ were 20–25–20–25, all given in seconds. The pulsing times were a function of the vapor pressure of the precursor. For TDMA-based precursors (titanium, tin and hafnium) 0.5 s at 150 °C process temperature was used and 0.2 s was the pulsing time only for the comparative case, at 250 °C process temperature. For the chloride precursor 0.05 s was used, and for demineralized water in all the cases 0.05 s was the pulsing time.⁴⁵ The process temperature in all cases was 150 °C. One further process was carried out at 250 °C with TDMA_n in order to evaluate the thermal impact of the ALD process on the substrate. For all coatings, a thickness of approximately 30 nm was targeted. In order to obtain this thickness, 440 ALD cycles were performed for a TiO₂ deposition with TDMA_n, calculated from the obtained growth rate of 0.73 Å per cycle. For the TiCl₄ process, 500 ALD cycles were applied, resulting in a growth rate of 0.66 Å per cycle. For the SnO₂ process, 380 ALD cycles (growth rate: 0.79 Å per cycle) at 150 °C and 200 cycles (growth rate: 1.50 Å per cycle) at 250 °C were applied. For the HfO₂ process, 400 ALD cycles were performed (growth rate: 0.82 Å per cycle).

After the ALD coating process (TiO₂ generation with TDMA_n and demineralized water), the coated, TDMA_n–FeO_x sample, and uncoated γ -Fe₂O₃ nanoparticles were subjected to *ex situ* annealing in order to crystallize the deposited film and make comparisons with the untreated particles. Both thermal treatments were carried out in air at atmospheric pressure and at 470 °C for 3 hours.⁴⁶

Structural characterization

Scanning transmission electron microscopy (STEM) images were acquired with a FEI Titan operating at 300 keV in scanning mode with a coupled energy-dispersive X-ray spectrometer (STEM-EDX). The samples were dissolved in ethanol and drop cast onto carbon coated copper grids. Powder X-ray diffraction (XRD) patterns were recorded with a PANalytical XPert Pro X-ray diffractometer using Cu K α radiation ($\lambda = 1.5405980$ Å) operating at 45 kV/40 mA in the 25–65° 2 θ range with a scan speed of 0.00144°·s⁻¹. Quantitative analysis of the XRD data was performed with a full pattern fitting procedure based on the fundamental parameter approach (Rietveld method) using MAUD software (<http://maud.radiographema.eu/>).

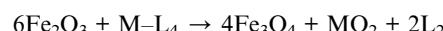
The magnetic properties of the nanoparticles were measured from tightly packed powder samples using a vibrating sample mode magnetometer (Quantum Design SQUID-VSM overcool) with a 70 kOe maximum field. Magnetization *versus* temperature measurements were performed under zero-field cooled (ZFC) and field cooled (FC) conditions with 50 Oe probe fields.

Computational methods

All the calculations in this work were performed using the density functional theory (DFT) method implemented in the

Vienna *ab initio* simulation package (VASP)^{47,48} with the projector-augmented wave (PAW) method.⁴⁹ The generalized gradient approximation (GGA) with the semilocal Perdew–Burke–Ernzerhof (PBE)⁵⁰ function was adopted to describe the exchange correlation interactions. The cutoff energy was set to be 450 eV. The structures were optimized with criteria of convergence for energy and force as 10⁻⁴ eV and 10⁻² eV Å⁻¹, respectively. On-site Coulomb repulsion of Fe 3d electrons was treated by Hubbard *U* correction⁵¹ with an effective *U* value *U*_{eff} = 4 eV according to previous theoretical reports.^{52,53}

The reaction tendency of reducing Fe₂O₃ to Fe₃O₄ with different ALD precursors was determined by the reaction energies of the following reaction:



where M–L₄ and L₂ denote the molecular ALD precursors and oxidation products, respectively. A negative reaction energy indicates that this reduction reaction can take place easily. If the reaction energy is positive, although the reduction reaction may still happen due to the entropy change as gas phase L₂ produced, it needs to at least overcome an activation barrier equal to the positive reaction energy.

The molecular precursors and oxidation products are modelled in a 20 Å × 20 Å × 20 Å supercell using the standard lattice parameters of all oxides.

Conclusions

In this work, we demonstrate that the ALD process not only coats nanoparticles in a controlled way, but also depending on the ligand of the metallic precursor, the substrate material is modified with respect to its final chemical and/or structural properties. γ -Fe₂O₃ nanoparticles have been coated with TiO₂ and concertedly reduced to magnetite. As a result, Fe₃O₄/TiO₂ core/shell nanoparticles have been generated by atomic layer deposition at moderate temperatures. The deposited coatings prevent agglomeration of the nanoparticles and re-oxidation to γ -Fe₂O₃ even at high temperatures, allowing for the use of post-process annealing and thus crystallization of the amorphous TiO₂ to anatase, a beneficial characteristic which has an important role in many industrial and bio-related applications.

The reduction of γ -Fe₂O₃ to Fe₃O₄ is a function of the applied precursor and the processing temperature. The ligand of the precursor (CH₃)₂N⁺ can become oxidized and recombine to form tetramethylhydrazine, while acting as a reducing agent for Fe³⁺. The cation of the precursor also plays an important role. The more electronegative the cation is, the more energy is necessary to release the ligands, which is important for the recombination. Therefore, the temperature required for ALD processes to reduce the sample is higher for TDMA_n than for TDMA_n and TDMAHf.

The use of an ALD process to concertedly coat and reduce nanomaterials simplifies numerous attempts to generate multifunctional materials for emerging applications, such as energy storage or medicine. The appropriate design of precursors and selection of substrates will pave the way for numerous



new compositions, while the ALD process itself allows for easy upscaling to large amounts of coated and reduced particles for industrial use.

Conflicts of interest

There are no conflicts to declare.

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